AMENDMENTS TO THE CLAIMS

- - an optical excitation source consisting of a semiconductor laser, emitting in the direction of a <u>sample of</u> <u>said</u> substance <u>sample</u>, a light beam whereof the wavelength, located in the mid infrared, corresponds to an absorption band specific of said element; and
 - the <u>a</u> means for detecting and measuring the heating effects of the hestsaid substance, resulting from the interaction of the element molecules excited by said beam with said host substance molecules,

wherein characterized in that the said source of excitation is a quantum cascade laser.

- 2. (Currently Amended) A device Device-according to claim 1, wherein characterized in that the said means for detecting and measuring, respond-responds to the pressure wave generated by heating the hostsaid substance, to produce a representation of the concentration of said element in said substance.
- 3. (Currently Amended) <u>A device Device-according to claim 2, wherein characterized in that the-said means for detecting and measuring comprises a microphone.</u>
- 4. (Currently Amended) A device Device-according to claim 2, wherein characterized in that the said means for detecting and measuring responds to the variation in the index of refraction of the host said substance, due to the pressure wave generated by the heating thereof, in order to produce a

representation of the concentration of said element in said substance.

- 5. (Currently Amended) A device Device according to claim 4, wherein characterized in that the said means for detecting and measuring comprise comprises a source of light emitting a sounding beam, which crosses said sample and the a means of measuring the deflection of said sounding beam, which results from the change in refraction index of the host said substance.
- 6. (Currently Amended) A device Device-according to claim 1, wherein characterized in that said means for detecting and measuring respond responds to the variation in the index of refraction of the host said substance, resulting from the heating thereof, to produce a representation of the concentration of said element in said substance.
- 7. (Currently Amended) A device Device-according to claim 6, wherein characterized in that the said means for detecting and measuring comprise comprises a source of light emitting a sounding beam which crosses said sample in a co-linear manner in relation to the excitation light beam and also comprise comprises a means of for measuring the enlargement of the sounding beam resulting from the change in the refraction index of the host said substance.
- 8. (Currently Amended) <u>A device Device according to claim 1, characterized in that it also comprises further comprising an enclosure to receive said sample.</u>

- 9. (Currently Amended) <u>A device Device-according to claim 8, wherein</u>

 characterized in that the enclosure is smaller than the
 acoustic wavelength at excitation working frequency.
- 10.(Currently Amended) A device Device-according to claim 8, wherein characterised in that the enclosure is of such dimension as to accommodate the acoustic modes resonating at excitation working frequency.
- 11.(Currently Amended) <u>A device Device-</u>for detecting by photoexcitation, a chemical element in a host substance comprising:
 - a source of optical excitation consisting of a semiconductor laser which, in the direction of the <u>a</u> sample of said substance, emits a beam of light, the wavelength of which, located in the mid infrared, corresponds to an absorption band specific to said element; and
 - the a means for detecting and measuring the heating effects of the host said substance, resulting from the interaction of the element molecules excited by said beam, with said host substance molecules,
 wherein characterized in that said source of excitation is a type II quantum well laser.
- 12. (Currently Amended) <u>A device Device-</u>for detecting by photoexcitation, a chemical element in a host substance comprising:
 - a source of optical excitation consisting of a semiconductor laser which, in the direction of the <u>a</u> sample of said substance, emits a beam of light, the wavelength of which, located in the mid infrared, corresponds to an absorption band specific to said element; and
 - the <u>a</u> means for detecting and measuring the heating effects of the host substance, resulting from the

interaction of the element molecules excited by said beam, with said host substance molecules,

wherein characterized in that said source of excitation is a type II quantum cascade laser.

- 13.(Currently Amended) <u>A device Device-</u>for detecting by photoexcitation, a chemical element in a host substance comprising:
 - a source of optical excitation consisting of a semiconductor laser which, in the direction of the-a sample of said substance, emits a beam of light, the wavelength of which, located in the mid infrared, corresponds to an absorption band specific to said element; and
 - the <u>a</u> means for detecting and measuring the heating effects of the host substance, resulting from the interaction of the element molecules excited by said beam, with said host substance molecules,

wherein characterized in that said source of excitation is a quantum well laser using materials with low forbidden band energy.